

Dual N-Channel MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$V_{DS}(V)$ $R_{DS(on)}(\Omega)$			
20	$0.024 \text{ at V}_{GS} = 4.5 \text{ V}$	6.0		
	0.028 at $V_{GS} = 2.5 \text{ V}$	5.0		

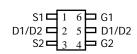
FEATURES

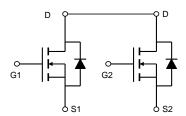
- Halogen-free Option Available
- TrenchFET $^{\text{®}}$ Power MOSFETs 100 % R_{g} Tested
- Compliant to RoHS Directive 2002/95/EC





TSOP6 **Top View**





ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	s otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	20		V	
Gate-Source Voltage		V _{GS}	± 12		V	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	6.0	5.2	Δ.	
	T _A = 70 °C		4.8	4.2		
Pulsed Drain Current		I _{DM}	30		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	1.5	1.0		
Mariana Barra Biratinati	T _A = 25 °C	Б	1.5	1.0	14/	
Maximum Power Dissipation ^a	T _A = 70 °C	P_{D}	0.96	0.64	W	
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Тур.	Max.	Unit	
Manimum lumation to Ambienta	t ≤ 10 s	R _{thJA}	72	83	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	'`thJA	100	120		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	55	70		

a. Surface Mounted on FR4 board, $t \le 10 \text{ s.}$

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.



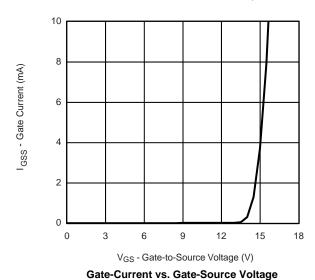
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions Min.		Typ. ^a	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$ 0.5			1.5	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 200	nA		
Zana Cata Valtana Busin Comment		V _{DS} = 20 V, V _{GS} = 0 V			1	μA		
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 70 °C	= 20 V, V _{GS} = 0 V, T _J = 70 °C					
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α		
5 1 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	В	$V_{GS} = 4.5 \text{ V}, I_D = 5.5 \text{ A}$	0.024			Ω		
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 2.5 V, I _D = 3.5 A		0.028				
Forward Transconductance ^b	9 _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 5.5 \text{ A}$		30		S		
Diode Forward Voltage ^b	V_{SD}	I _S = 1.5 A, V _{GS} = 0 V		0.71	1.2	V		
Dynamic ^a								
Total Gate Charge	Q_g			12	18			
Gate-Source Charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 5.5 \text{ A}$		2.2		nC		
Gate-Drain Charge	Q_{gd}			3.6				
Turn-On Delay Time	t _{d(on)}			245	365			
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		330	495	1		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 4.5 V, R_G = 6 Ω		860	1300	ns		
Fall Time	t _f			510	765			

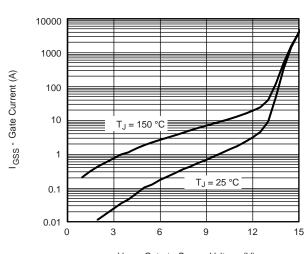
Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

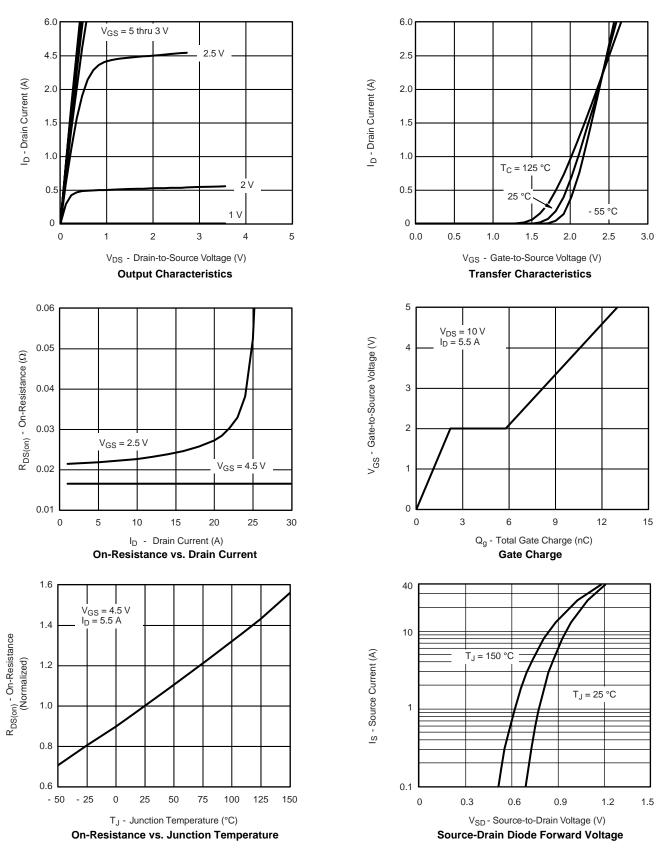




 $\label{eq:VGS} V_{GS} \text{ - Gate-to-Source Voltage (V)}$ Gate Current vs. Gate-Source Voltage

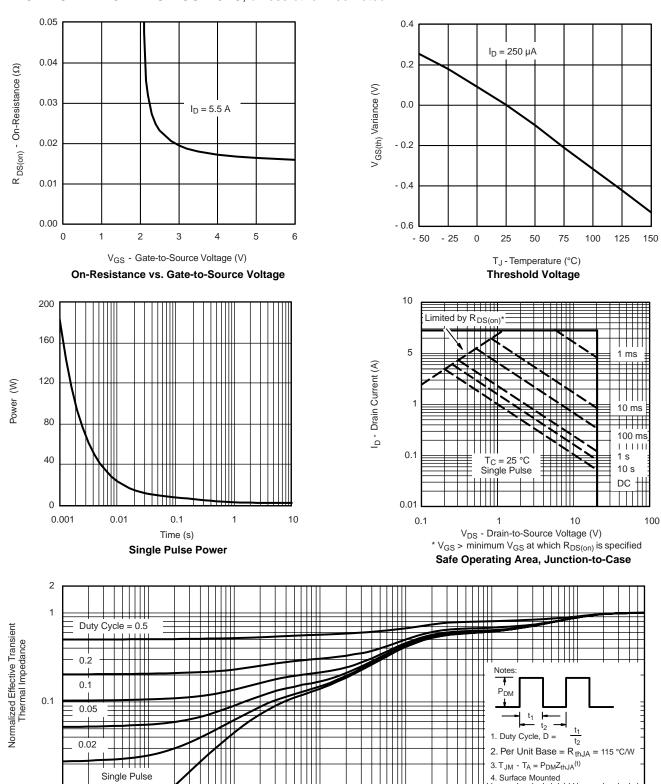


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Ambient

10-1

10-2

服务热线:400-655-8788

600

100

10

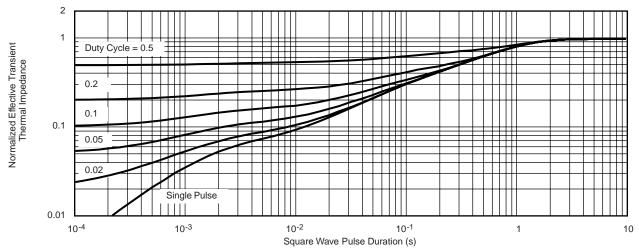
0.01

10-4

10-3



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

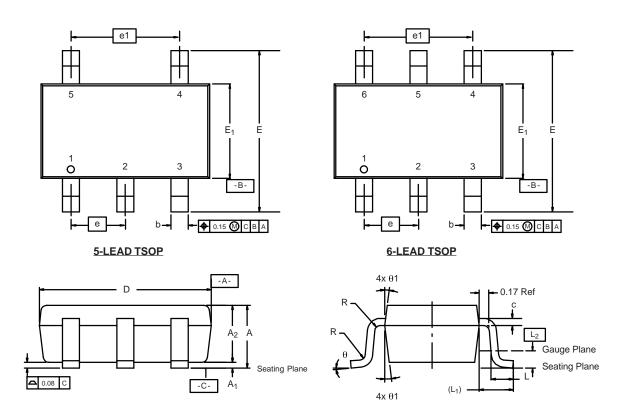


Normalized Thermal Transient Impedance, Junction-to-Foot



TSOP: 5/6-LEAD

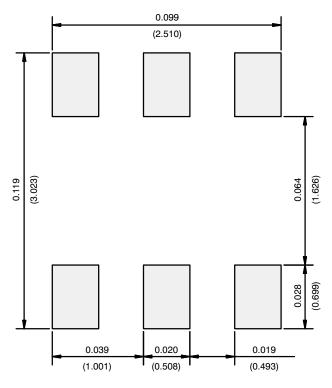
JEDEC Part Number: MO-193C



	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.079		
L	0.32	-	0.50	0.012	-	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom			7° Nom			
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							



RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)



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